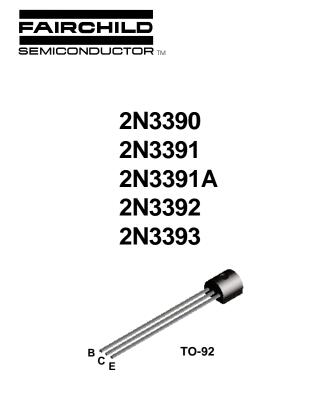
Discrete POWER & Signal **Technologies** 



## **NPN General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100A for characteristics.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
V <sub>CBO</sub>	Collector-Base Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous	500	mA
TJ, Tsta	Operating and Storage Junction Temperature Range	-55 to +150	۰C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### **Thermal Characteristics** TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах	Units
		2N3390 / 3391/A / 3392 / 3393	
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
R <sub>0JC</sub>	Thermal Resistance, Junction to Case	83.3	°C/W
R <sub>0JA</sub>	Thermal Resistance, Junction to Ambient	200	°C/W

# NPN General Purpose Amplifier (continued)

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Symbol	Parameter Test Conditions		Min	Max	Units
OFF CHA	RACTERISTICS				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown     I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0       Voltage*     Voltage = 0		25		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 10 \ \mu A, I_{E} = 0$	25		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \ \mu A, \ I_C = 0$	5.0		V
I <sub>CBO</sub>	Collector-Cutoff Current	$V_{CB} = 18 \text{ V}, I_E = 0$		100	nA
I <sub>EBO</sub>	Emitter-Cutoff Current	$V_{EB} = 5.0 \text{ V}, I_{C} = 0$		100	nA
ON CHAR	ACTERISTICS* DC Current Gain	$V_{CE} = 4.5 \text{ V}, \text{ I}_{C} = 2.0 \text{ mA}$ 2N3390 2N3391/A 2N3392	400 250 150	800 500 300	
		2N3393	90	180	

## SMALL SIGNAL CHARACTERISTICS

C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, f = 1.0 MHz	2.0	10	pF
h <sub>fe</sub>	Small-Signal Current Gain	$\label{eq:loss} \begin{array}{l} I_{C} = 2.0 \text{ mA}, \ V_{CE} = 4.5 \text{ V}, \\ f = 1.0 \text{ kHz} & \textbf{2N3390} \\ & \textbf{2N3391/A} \\ & \textbf{2N3392} \\ & \textbf{2N3393} \end{array}$	400 250 150 90	1250 800 500 400	
NF	Noise Figure			5.0	dB

\*Pulse Test: Pulse Width  $\leq 300~\mu\text{s},~\text{Duty}~\text{Cycle} \leq 2.0\%$ 

2N3390 / 2N3391 / 2N3391A / 2N3392 / 2N3393



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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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